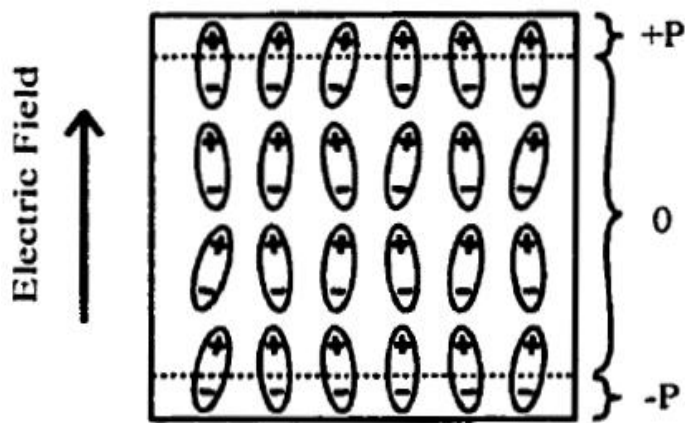


# **fabrication of PZT film**

## **measure of hysteresis loop**

발표자 : 이재진

# Ferroelectrics



Representation of the dipoles in a dielectric material placed in an electric field

In the presence of an external electric field, dielectric materials have the ability to form and align internal dipoles

at the edges the aligned dipoles effectively act as surface charges  $P$

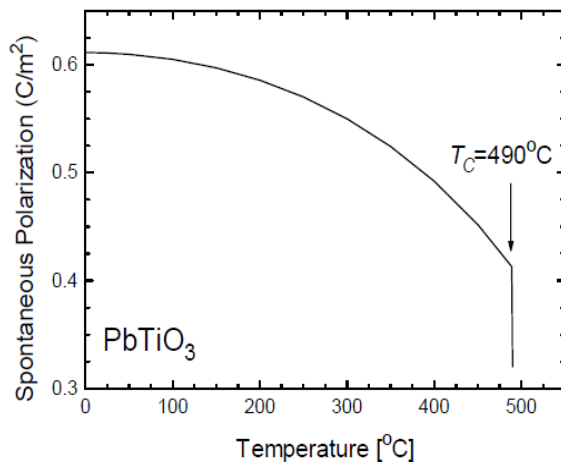
While most dielectrics will lose their polarization after the removal of the external field

some remain polarized. In an analogy to magnetism, the special subclass of dielectrics to which these materials belong is called ferroelectrics

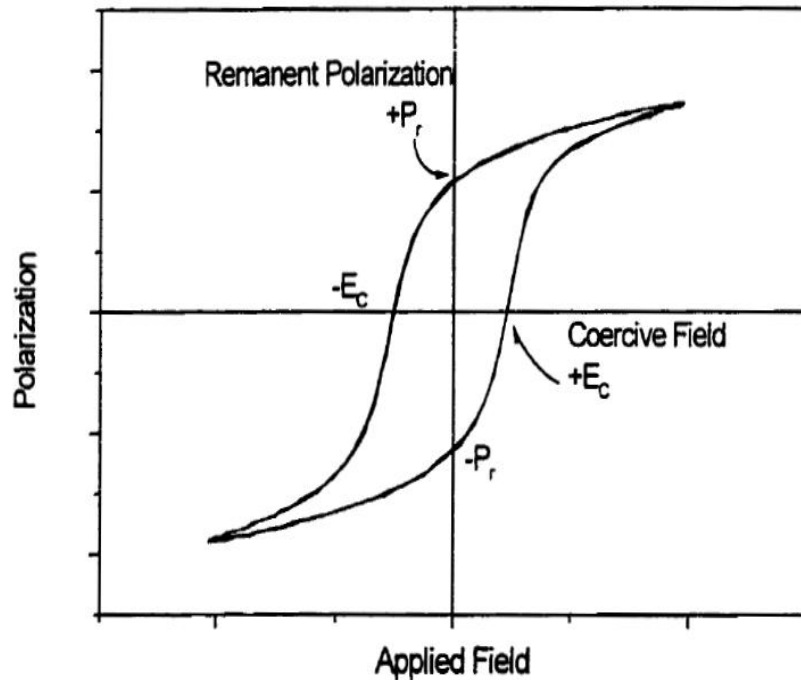
some remain polarized. In an analogy to magnetism, the special subclass of dielectrics to which these materials belong is called ferroelectrics

Curie temperature  $T_c$

at which the remanent polarization disappears



# Hysteresis loop



Remanent polarization( $P_r$ ) :

the surface charge that remains after the removal of the external field (because spontaneous polarization)

Coercive Field( $E_c$ ) :

To change the direction of polarization of the size of the critical electric field

Internal area of the hysteresis curve :

electrical energy required for switching of the polarization

# PZT(Pb(Zr, Ti)O<sub>3</sub>)

## Characteristic

- Spontaneous polarization in the absence applied electrical field
- Extremely high dielectric constant (~500-15,000)
- Strong non-linear dielectric response to an applied electrical field
- High strain response to applied electrical field (piezoelectricity)
- Strong variation in polarization with temperature (piezoelectricity)

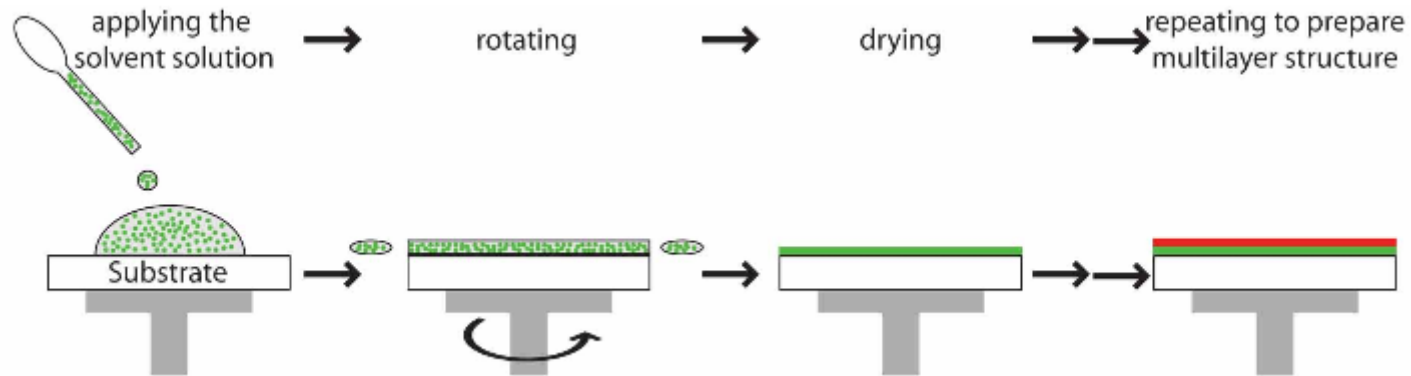
## Pb(Zr, Ti)O<sub>3</sub>

- PbZrO<sub>3</sub> + PbTiO<sub>3</sub>
- Zr : Ti (PbTiO<sub>3</sub> is also increased with increasing permittivity)

Zr : Ti	20 : 80	30 : 70	40 : 60	52 : 48
permittivity	614	729	899	939

# Fabrication of pzt film

## Spin coating



Spin coating is a cheap and fast method to produce homogeneous layers

The film thickness can be adjusted by varying the rotation speed, the rotation time and the concentration of the used solution.

The disadvantage of this method is that it is limited by the solvent and that no lateral resolution is possible.

# Fabrication of pzt film

## Spin coating

WET 세척, UV세척, UV건조

Spin coating  
4000rpm for 25sec.

Baking 1  
450 °C for 10min. Using Furnace

Baking 2  
650 °C for 2min. Using Furnace

Final Annealing  
650 °C for 30min. Using Furnace

상부전극 증착

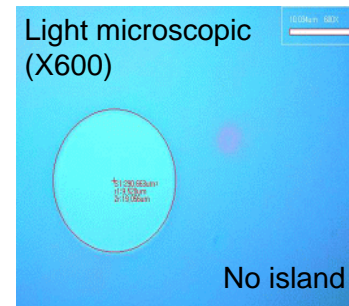
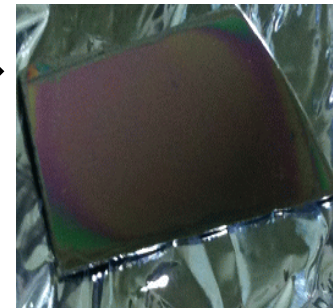
repeat



Spin coater



furnace



## Annealing :

improves the crystallization and the electric properties of the film

# Fabrication of pzt film

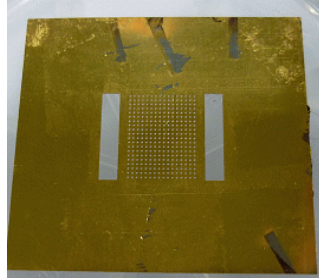
## Electron beam evaporation



E-beam intensity : 89mA

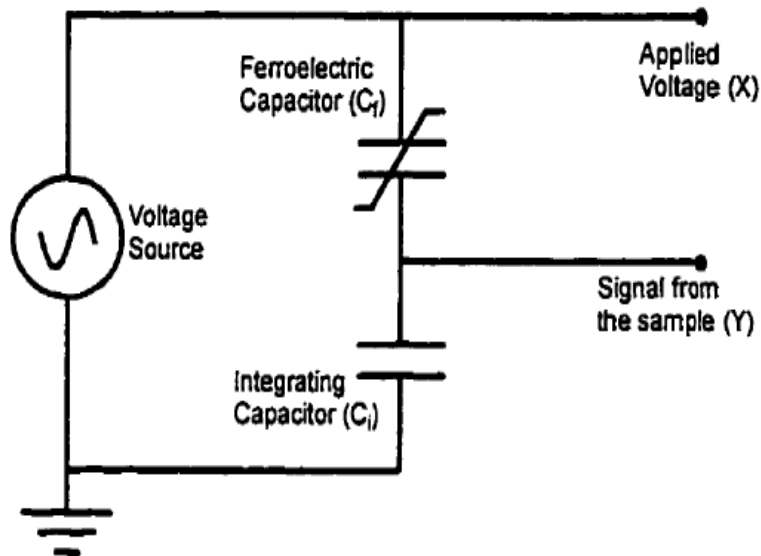
Au evaporation : evaporation rate 0.5Å/s  
thickness 500Å

Vacuum condition :  $1.1 \times 10^{-6}$  torr



# Fabrication of pzt film

Sawyer-tower



In a circuit composed of two capacitors in series, the charges accumulating on each capacitor are equal. Realizing that the polarization  $P$  is given by

$$P = \frac{Q_f}{A_f}$$

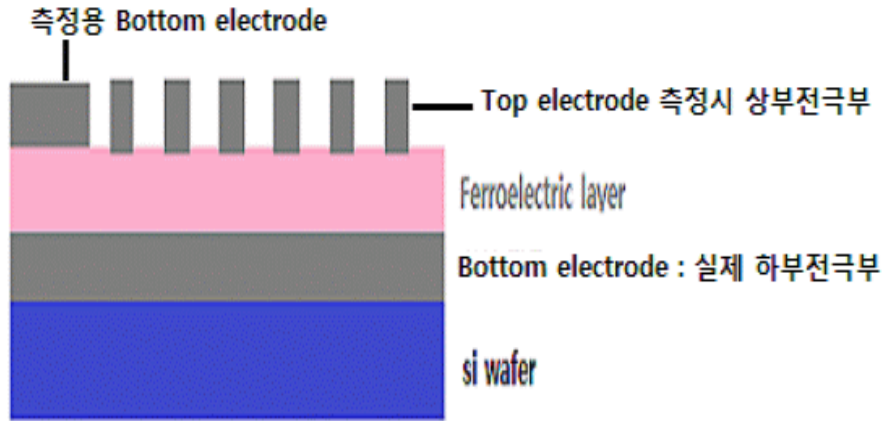
where  $Q$ , is the charge on the ferroelectric capacitor and  $A$ , the area of the electrode and that the charge on both capacitors are equal, the polarization is then given by

$$P = \frac{Q_i}{A_f} = \frac{C_i \times V_i}{A_f}$$



# Fabrication of pzt film

how can we measure polarization?



Resistance of ferroelectric layer

$$R = \frac{\rho \times t}{A}$$

R : resistance

A : area

$\rho$  : resistivity

t : thickness

considering ferroelectric layer resistance

We think Series resistance circuit

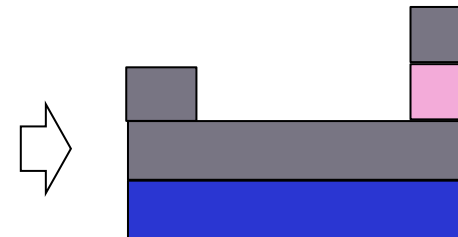
$$R = R_1 + R_2 = \frac{\rho \times t}{A_1} + \frac{\rho \times t}{A_2}$$

$A_1$  : top electrode

$A_2$  : bottom electrode

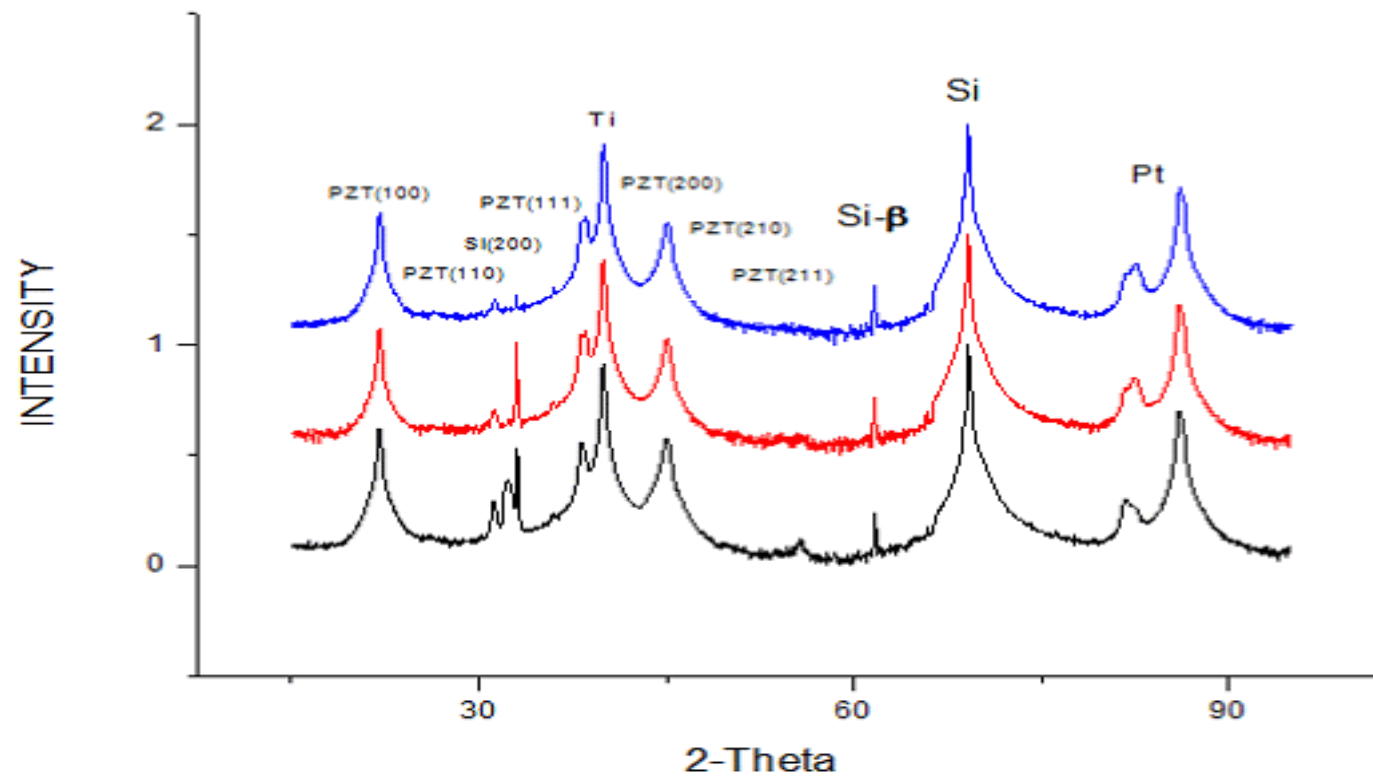
$$A_1 \gg A_2$$

$$R = R_1 + R_2 \approx \frac{\rho \times t}{A_2} = R_2$$



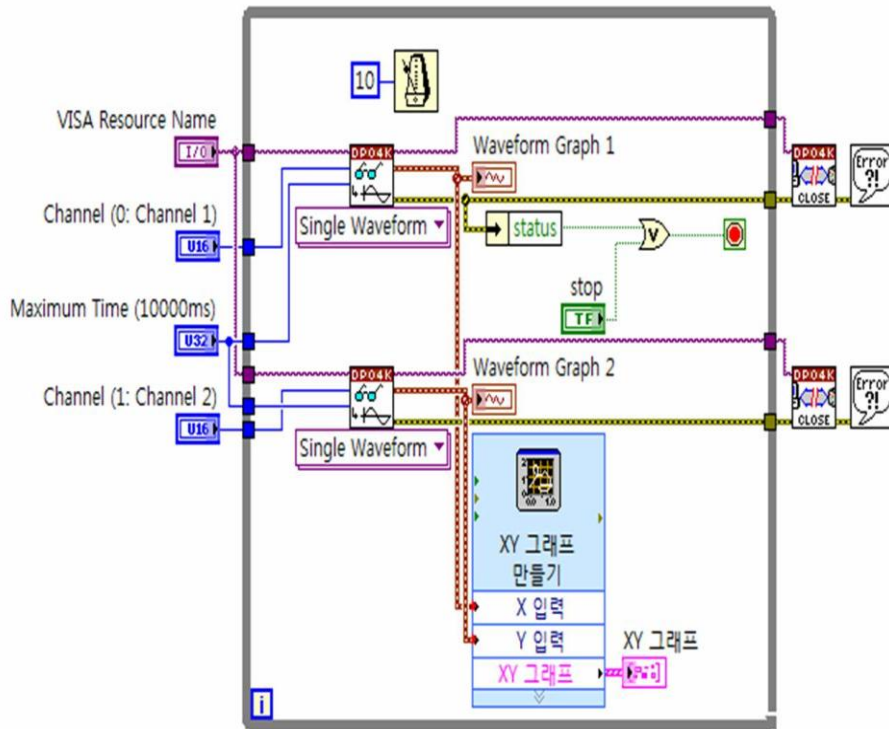
# Result

XRD(X-ray Diffraction) graph

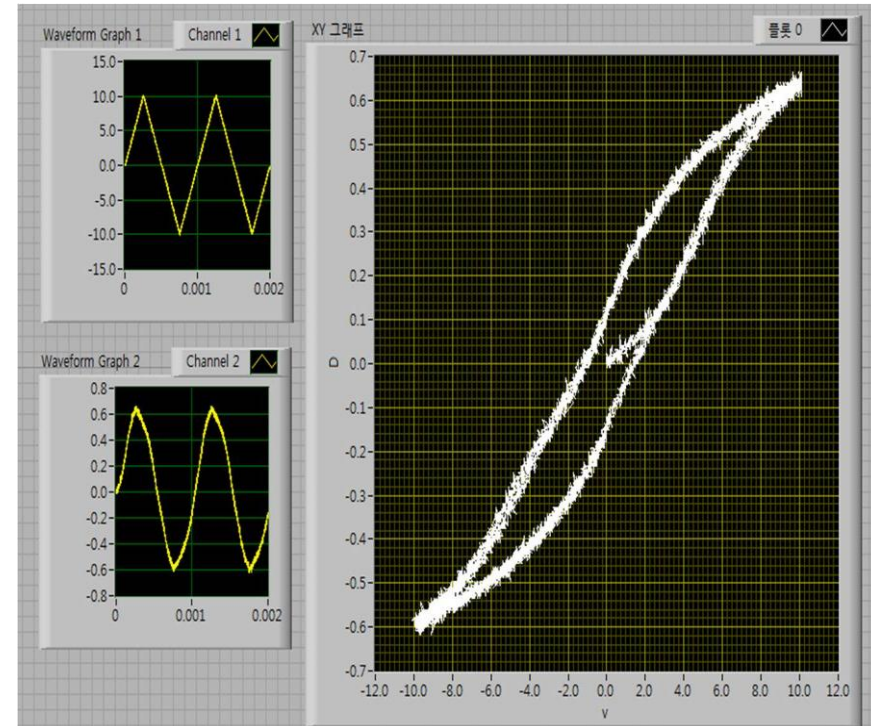


# Result

measure of hysteresis loop by using LabVIEW



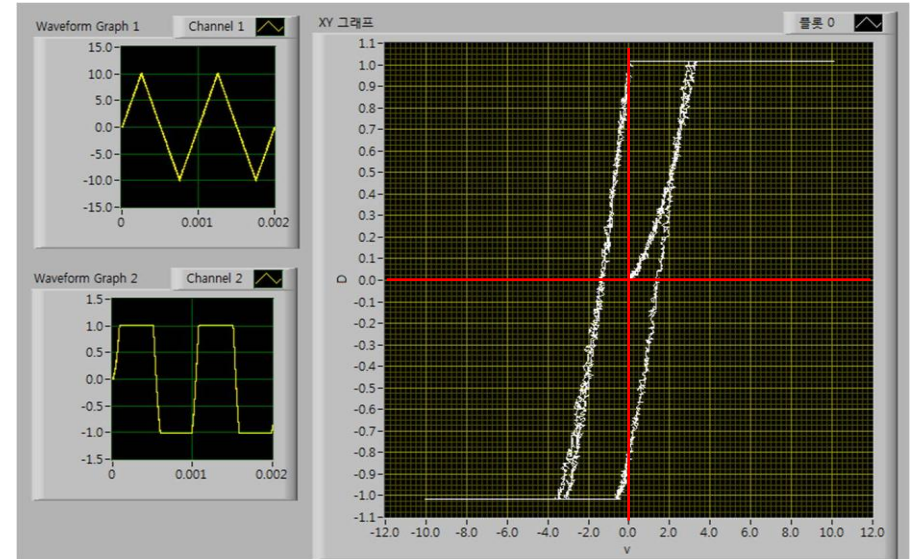
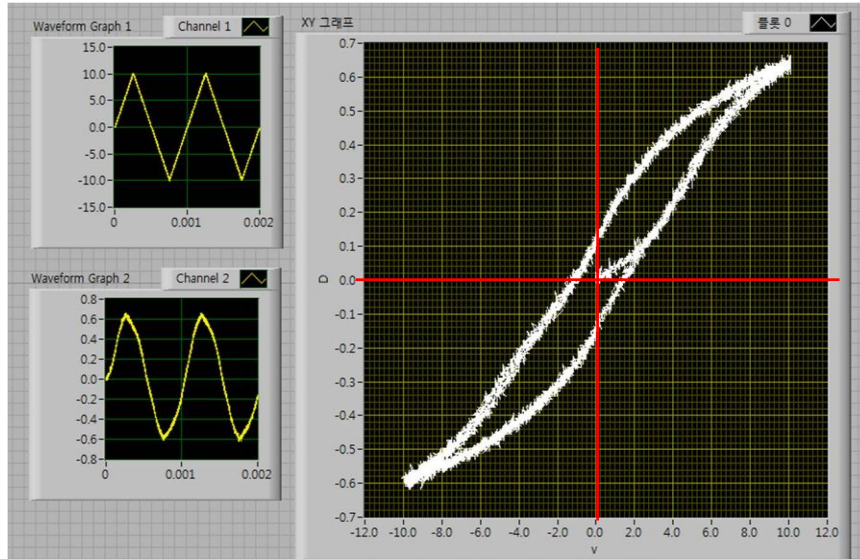
Block diagram



Front panel

# Result

measure of hysteresis loop by using LabVIEW



	$P_s(c/m^2)$	$P_r(c/m^2)$	$E_c (V)$
Sample1	20.37	3.81	1.6
Sample2	16.98	14.15	1.2